Result of PID cell test benchmark



PIDcon by Freiberg Instruments

PID cell test conditions:

Temperature: 85 °C

Voltage: 1000 V (neg. on cell, pos. on glass)

Stressed area: 10x10 cm²

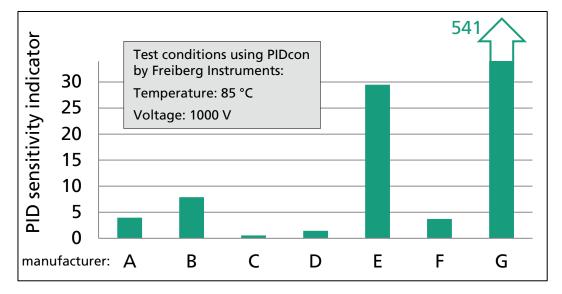
Polymer encapsulating foil:

PID sensitive EVA with low resistivity:

Avaluxe EVA-FL TL MG ARC2

Glass: low-iron float glass, 3.2 mm

- Result: <u>shunt conductance</u> (= reciprocal of shunt resistance) as a function of <u>transferred charge</u> (= accumulated stress) → <u>genuine PID-s sensitivity of cells</u>
- Evaluation of the maximum slope of PID shunt conductance over accumulated charge curves → PID sensitivity indicator in units of (mS/cm²)/(µAh/cm²)
- Production batches of different manufacturers equally tested:



PID sensitivity indicator, mean of 5 cells of each cell batch, published on www.pidcon.com